

MMBZ5V6ALT1G ESD PROTECTION DIODE

Discription

The MMBZ5V6ALT1G protects sensitive semiconductor components from damage or upset due to electrostatic discharge (ESD) and other voltage induced transient events. Excellent clamping capability, low leakage, low capacitance, and fast response time provide best in class protection on designs that are exposed to ESD. It gives designer the flexibility to protect 2 unidirectional

Features

- SOT-23 package allows either two separate unidirectional configurations or a single bidirectional configuration.
- ♦ Working peak reverse voltage 3V
- Standard Zener breakdown voltage 5.6V

line in applications where arrays are not practical.

- Peak power 24 or Watts @ 1.0ms (unidirectional) per Figure 6 Waveform
- ♦ESD Rating:
 - Class 3B (>16kV) per the Human Body Model Class C (>400V) per Machine Model
- \Rightarrow ESD Rating of IEC61000-4-2 level 4, \pm 30kV contact Discharge
- ⊹Low leakage < 5.0µA</p>

Ordering information

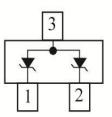
Product ID	Pack	Qty(PCS)
MMBZ5V6ALT1G	SOT-23	3000

Absolute Ratings (T_{amb}=25°C)

Symbol	Parameter		Value	Units
P _{PP}	Peak Pulse Power (t _P = 8/20µs)	24	W	
ΤL	Maximum lead temperature for soldering during 10s		260	°C
T _{stg}	Storage Temperature Range	-55 to +150	°C	
T _{op}	Operating Temperature Range		-40 to +125	°C
Tj	Maximum junction temperature		150	°C
	IEC61000-4-2 (ESD) cor	air discharge ntact discharge	±30 ±30	KV







Circuit Diagram



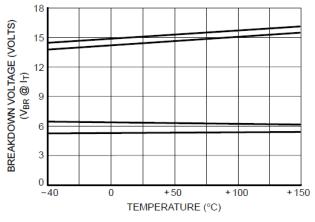
ELECTRICAL CHARACTERISTICS (Tamb=25°C) UNIDIRECTIONAL (Circuit tied to Pins 1 and 3 or Pins 2 to 3)

		V_{RWM}	I _R	V_{BR}			V _{BR} Z _{ZT} Z _{ZK} V _C		Z _{ZK}		/c	
Part Number	Device Marking	(V)	(µA)		(V)		(mA)	(Ω)	(Ω)	(mA)	(V)	(A)
			@ V _{RWM}	Min	Nom	Max	@ I⊤	Max @I _{zt}	Max	@ І _{ZK}	Max	@ I _{PP}
MMBZ5V6ALT1G	5A6	3.0	5.0	5.32	5.6	5.88	20	11	1600	0.25	8.0	3.0

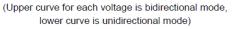


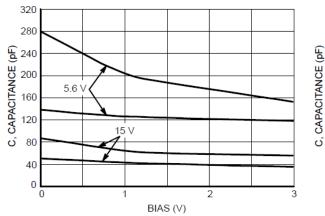
MMBZ5V6ALT1G ESD PROTECTION DIODE

ELECTRICAL CHARACTERISTICS CURVE











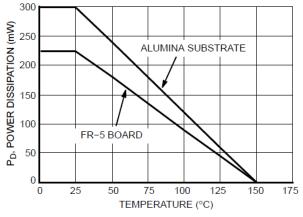


Figure 5. Steady State Power Derating Curve

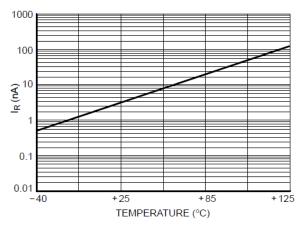


Figure 2. Typical Leakage Current versus Temperature

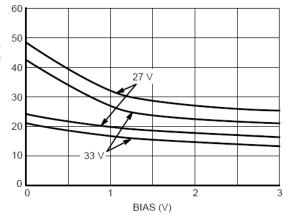


Figure 4. Typical Capacitance versus Bias Voltage (Upper curve for each voltage is unidirectional mode, lower curve is bidirectional mode)



MMBZ5V6ALT1G ESD PROTECTION DIODE

ELECTRICAL CHARACTERISTICS CURVE

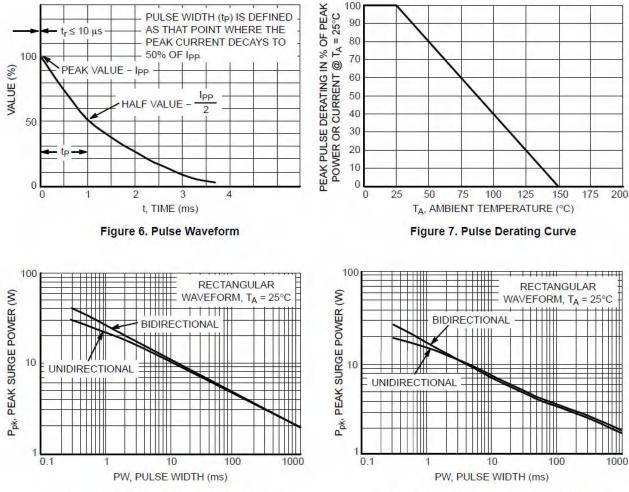


Figure 8. Maximum Non-repetitive Surge Power, P_{pk} versus PW

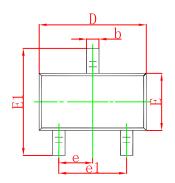
Power is defined as $V_{RSM} x I_Z(pk)$ where V_{RSM} is the clamping voltage at $I_Z(pk)$.

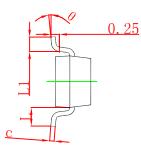
Figure 9. Maximum Non-repetitive Surge Power, P_{pk}(NOM) versus PW

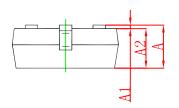
Power is defined as $V_Z(NOM) \times I_Z(pk)$ where $V_Z(NOM)$ is the nominal Zener voltage measured at the low test current used for voltage classification.



SOT-23 Package Outline Dimensions

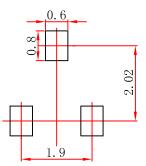






Symbol	Dimensions	In Millimeters	Dimensions In Inches			
Symbol	Min	Max	Min	Max		
Α	0.900	1.150	0.035	0.045		
A1	0.000	0.100	0.000	0.004		
A2	0.900	1.050	0.035	0.041		
b	0.300	0.500	0.012	0.020		
С	0.080	0.150	0.003	0.006		
D	2.800	3.000	0.110	0.118		
Е	1.200	1.400	0.047	0.055		
E1	2.250	2.550	0.089	0.100		
e	0.950	50 TYP 0.037 TYP		0.950 TYP		7 TYP
e1	1.800	2.000	0.071	0.079		
L	0.550) REF	0.022 REF			
L1	0.300	0.500	0.012	0.020		
θ	0°	8°	0°	8°		

SOT-23 Suggested Pad Layout



Note:

1.Controlling dimension: in millimeters.

2.General tolerance:± 0.05mm.
 3.The pad layout is for reference purposes only.



Attention

Any and all HUA XUAN YANG ELECTRONICS products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your HUA XUAN YANG ELECTRONICS representative nearest you before using any HUA XUAN YANG ELECTRONICS products described or contained herein in such applications.

• HUA XUAN YANG ELECTRONICS assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all HUA XUAN YANG ELECTRONICS products described or contained herein.

• Specifications of any and all HUA XUAN YANG ELECTRONICS products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.

• HUA XUAN YANG ELECTRONICS CO.,LTD. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could

give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.

• In the event that any or all HUA XUAN YANG ELECTRONICS products(including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.

• No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of HUA XUAN YANG ELECTRONICS CO.,LTD.

Information (including circuit diagrams and circuit parameters) herein is for example only ; it is not guaranteed for volume production.
HUA XUAN YANG ELECTRONICS believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.

Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the HUA XUAN YANG ELECTRONICS product that you intend to use.